

**MOC205 , MOC206 , MOC207 , MOC208,  
MOC211 , MOC212 , MOC213 ,  
MOC215 , MOC216 , MOC217**



## SMALL OUTLINE OPTICALLY COUPLED ISOLATOR TRANSISTOR OUTPUT

### DESCRIPTION

This series of optically coupled isolators consist of a Gallium Arsenide infrared emitting diode and NPN silicon photo transistor mounted in a standard 8 pin SOIC package, which makes them ideally suited for high density applications with limited space.

### FEATURES

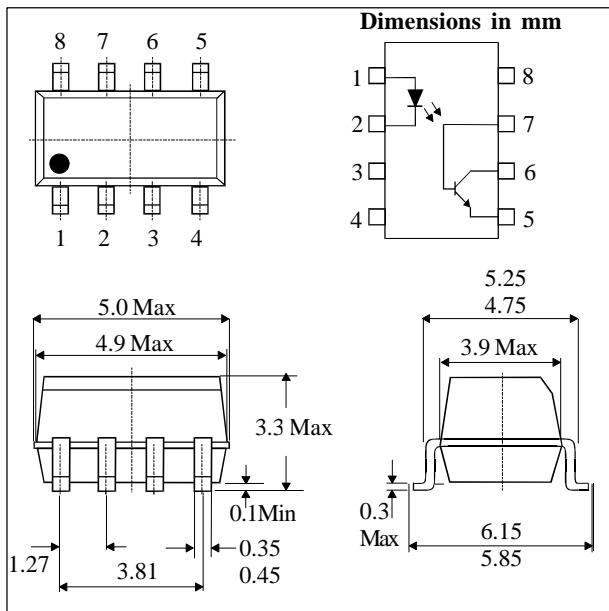
- Standard SOIC-8 Footprint with 0.05" Lead Spacing
- Specified min. and max. CTR at 10mA  $I_F$ , 10V  $V_{CE}$   
MOC205, 40-80%  
MOC206, 63-125%  
MOC207, 100-200%  
MOC208, 160-320%
- Specified minimum CTR at 10mA  $I_F$ , 10V  $V_{CE}$   
MOC211, 20%  
MOC212, 50%  
MOC213, 100%
- Specified minimum CTR at 1mA  $I_F$ , 5V  $V_{CE}$   
MOC215, 20%  
MOC216, 50%  
MOC217, 100%
- Isolation Voltage, 2500V<sub>RMS</sub>
- High  $BV_{CEO}$  (70V min)
- All electrical parameters 100% tested
- Available in Tape and Reel - add suffix "T&R"
- Custom electrical selections available

### ABSOLUTE MAXIMUM RATINGS (25°C unless otherwise noted)

Storage Temperature \_\_\_\_\_ -55°C to +125°C  
Operating Temperature \_\_\_\_\_ -55°C to +100°C  
Lead Soldering Temperature \_\_\_\_\_ 260°C  
(single wave for 10 secs)  
Input to Output Isolation Voltage \_\_\_\_\_ 2500V<sub>RMS</sub>

### INPUT DIODE

Forward Current \_\_\_\_\_ 60mA  
Reverse Voltage \_\_\_\_\_ 6V  
Peak Forward Current ( $t_p \leq 10\mu s$ ) \_\_\_\_\_ 3A  
Power Dissipation \_\_\_\_\_ 100mW  
(derate linearly 1.33mW/°C above 25°C)  
Junction Temperature \_\_\_\_\_ 125°C



### APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Hybrid substrates that require high density mounting
- Signal transmission between systems of different potentials and impedances

### OUTPUT TRANSISTOR

Collector-emitter Voltage  $BV_{CEO}$  \_\_\_\_\_ 70V  
Emitter-collector Voltage  $BV_{ECO}$  \_\_\_\_\_ 7V  
Collector-base Voltage  $BV_{CBO}$  \_\_\_\_\_ 70V  
Collector Current \_\_\_\_\_ 50mA  
Collector Current \_\_\_\_\_ 100mA  
(pw ≤ 10ms, 50% duty ratio)  
Power Dissipation \_\_\_\_\_ 150mW  
(derate linearly 2.00mW/°C above 25°C)  
Junction Temperature \_\_\_\_\_ 125°C

### PACKAGE

Total Power Dissipation \_\_\_\_\_ 250mW  
(derate linearly 3.3mW/°C above 25°C)

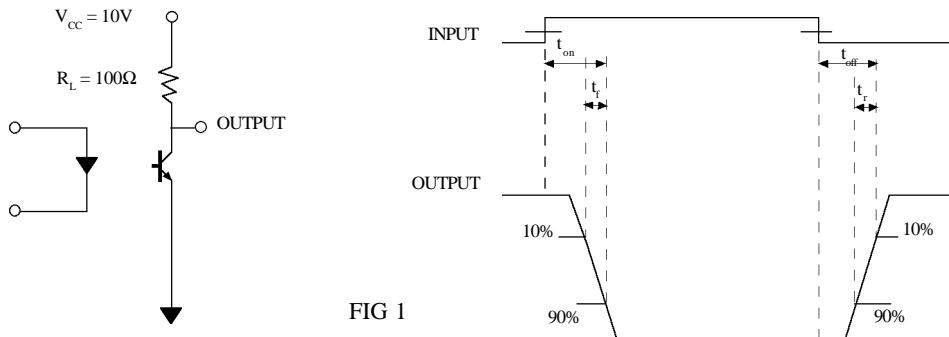
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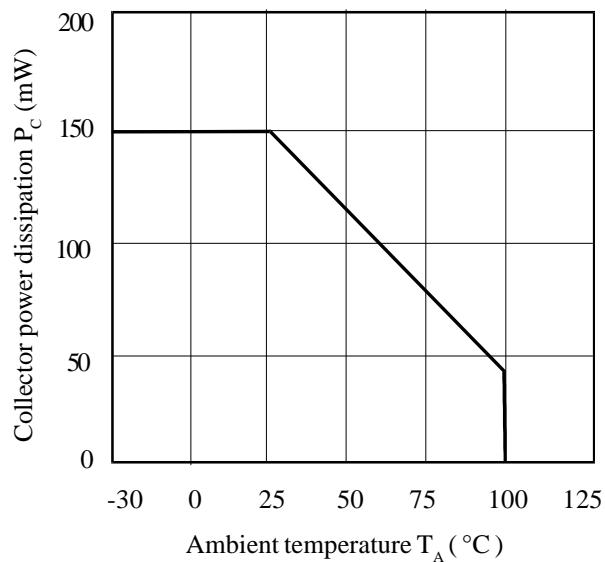
## ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input	Forward Voltage ( $V_F$ ) Capacitance Reverse Current ( $I_R$ )		1.2 50	1.5 100	Volt pF μA	$I_F = 10 \text{ mA}$ $V_R = 0, f = 1 \text{ MHz}$ $V_R = 6V$
Output	Collector-emitter Voltage ( $BV_{CEO}$ ) Emitter-collector Voltage ( $BV_{ECO}$ ) Collector-base Voltage ( $BV_{CBO}$ ) Collector-emitter Dark Current ( $I_{CEO}$ )	70 7 70		50	Volt Volt Volt nA	$I_C = 100 \mu\text{A}$ $I_E = 100 \mu\text{A}$ $I_C = 100 \mu\text{A}$ $V_{CE} = 10V$
Coupled	Current Transfer Ratio (CTR) MOC205 MOC206 MOC207 MOC208 MOC211 MOC212 MOC213 MOC205 MOC206 MOC207 MOC208 MOC215 MOC216 MOC217 Collector-emitter Saturation Voltage $V_{CE(SAT)}$ (MOC205 to MOC213) Collector-emitter Saturation Voltage $V_{CE(SAT)}$ (MOC215 to MOC217) Capacitance Input to Output ( $C_{ISO}$ ) Input to Output Isolation Resistance ( $R_{ISO}$ ) Input to Output Isolation Voltage ( $V_{ISO}$ ) Output Turn on Time ( $t_{on}$ ) Output Turn off Time ( $t_{off}$ ) Output Rise Time ( $t_r$ ) Output Fall Time ( $t_f$ )	40 63 100 160 20 50 100 13 22 34 56 20 50 100 2500	80 125 200 320 % % % % % % % % 0.4 0.4 0.3 10 <sup>11</sup> V <sub>RMS</sub> μs μs μs μs	% % % % % % % % % % % % % % % %		$I_F = 10 \text{ mA}, V_{CE} = 10V$ $I_F = 1 \text{ mA}, V_{CE} = 10V$ $I_F = 1 \text{ mA}, V_{CE} = 5V$ $I_F = 10 \text{ mA}, I_C = 2 \text{ mA}$ $I_F = 1 \text{ mA}, I_C = 0.1 \text{ mA}$ $f = 1 \text{ MHz} (\text{note 1})$ $V_{IO} = 500V (\text{note 1})$ Note 1 $I_C = 2 \text{ mA},$ $V_{CC} = 10V, R_L = 100\Omega$

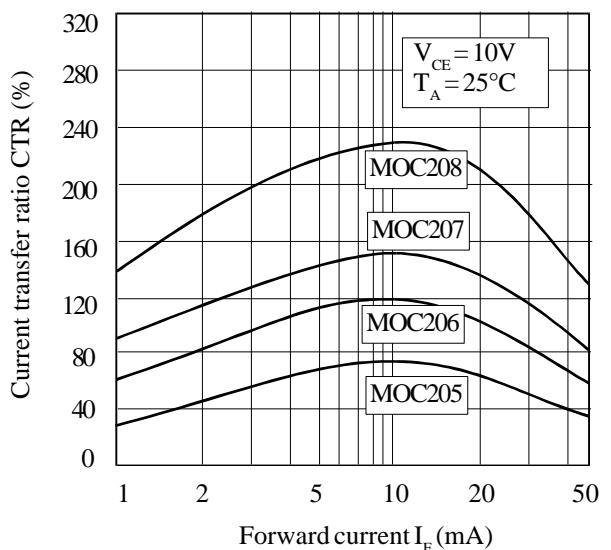
Note 1. Measured with input leads shorted together and output leads shorted together.



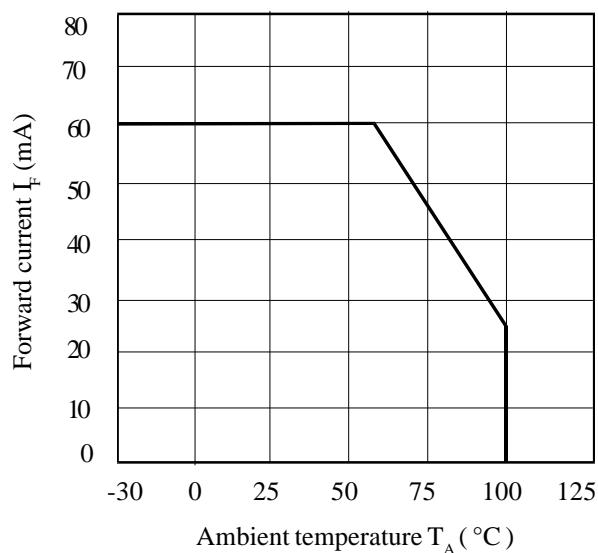
**Collector Power Dissipation vs. Ambient Temperature**



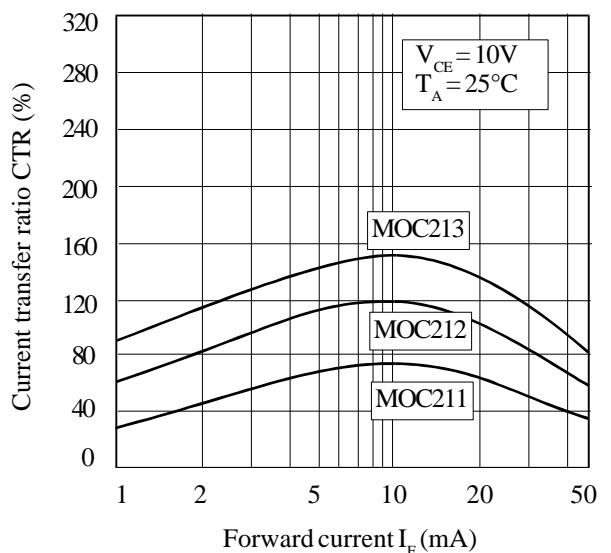
**Current Transfer Ratio vs. Forward Current**



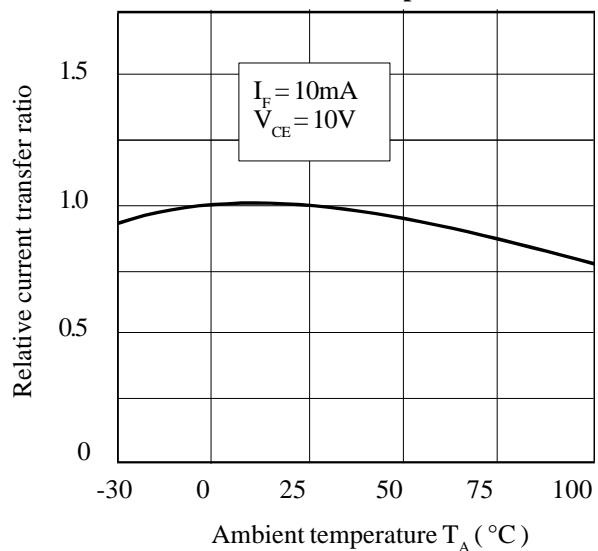
**Forward Current vs. Ambient Temperature**



**Current Transfer Ratio vs. Forward Current**



**Relative Current Transfer Ratio vs. Ambient Temperature**



**Current Transfer Ratio vs. Forward Current**

